

7-Channel Combo TVS

General Description

The AOZ8936DI is a multi-channel combo transient voltage suppressor array designed to protect high speed data lines such as USB3.1, USB2.0,and VBUS from damaging ESD events.

This device incorporates 2 channels for USB2.0, 4 channels for USB3.1 and 1 channel for VBUS.

The AOZ8936DI comes in a RoHS compliant and Halogen Free DFN4.1x2.0 package and is rated for -40°C to +125°C junction temperature range.

Features

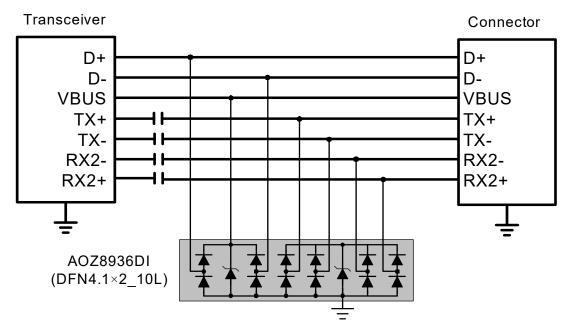
- IEC61000-4-2, ESD immunity (Contact/Air):
 - ± 30/30 kV (USB 3.1)
 - ± 24/30 kV (USB 2.0)
 - $-\pm 30/30$ kV (VBUS)
- IEC61000-4-5, Surge Immunity (8/20μs):
 - ± 6 A (USB 3.1)
 - ± 4 A (USB 2.0)
 - $-\pm 15 A (VBUS)$
- Capacitance between I/O to GND:
 - -0.4pF (USB 3.1)
 - 1.75pF (USB 2.0)
 - 120pF (VBUS)

Applications

- USB 3.1/3.2 & USB 2.0
- Monitors and flat panel displays
- Set-top-box
- Notebook computers



Typical Application





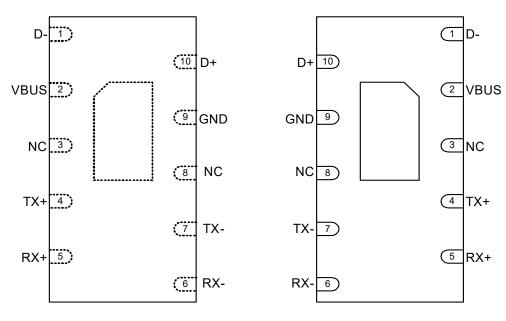
Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8936DI	-40°C to +125°C	DFN4.1X2_10L	Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Pin Configuration



Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Top View

Parameter	Rating						
	Pin 1 & Pin 10 (USB 2.0)	Pin 4 to Pin 7 (USB 3.1/3.2)	Pin 2 (VBUS)				
Storage Temperature (T _S)	-65°C to +150°C	-65°C to +150°C	-65 °C to +150°C				
ESD Rating per IEC61000-4-2, contact ⁽¹⁾	±24 kV	±30 kV	±30 kV				
ESD Rating per IEC61000-4-2, air ⁽¹⁾	±30 kV	±30 kV	±30 kV				
8/20µs Surge IEC61000-4-5	±4 A	±6 A	±15 kV				

Bottom View

Notes

- 1. IEC 61000-4-2 discharge with $C_{Discharge}$ = 150pF, $R_{Discharge}$ = 330 Ω .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100pF, $R_{Discharge}$ = 1.5k Ω .

Maximum Operating Ratings

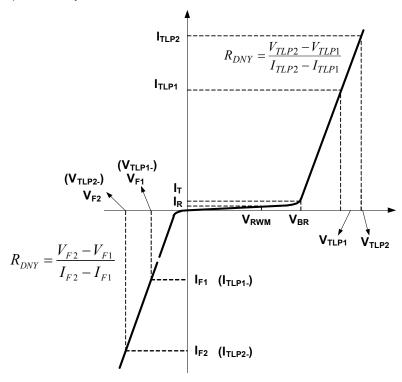
Parameter	Rating
Junction Temperature (T _J)	-40°C to +125°C

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Electrical Characteristics

 T_A = 25°C unless otherwise specified. Any I/O Pin to GND.



	Pin1 & Pin 10 (D+, D- of USB 2.0)									
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units				
V _{RWM}	Reverse Working Voltage				5.5	V				
V _{BR}	Reverse Breakdown Voltage	I _T = 100μA	6.6			V				
I _R	Reverse Leakage Current	V _T = Max, V _{RWM}			1	μΑ				
V _F	Forward Voltage		0.7	0.85	0.95	V				
V _{CL}	Clamping Voltage ⁽³⁾⁽⁴⁾ (100ns Transmission Line Pulse)	I _{TLP} = 1A I _{TLP} = -1A		11 -1.5		V				
* CL		I _{TLP} = 16A I _{TLP} = -16A		18 -7.5						
R _{DNY}	Dynamic Resistance ⁽³⁾⁽⁴⁾	I _{TLP} = 1A to 16A I _{TLP} = -1A to -16A			0.45 0.40	Ω				
I _{PP}	Peak Pulse Current ⁽³⁾ IEC61000-4-5 Surge 8/20μs	Any I/O Pin to GND GND to any I/O Pin			±4	Α				
V	Clamping Voltage ⁽³⁾ IEC61000-4-5 Surge 8/20µs	I _{PP} = 1A I _{PP} = -1A		10 -2		- V				
V_{CL}		I _{PP} = 4A I _{PP} = -4A		12.5 -4.5						
C _j	Junction Capacitance ⁽³⁾	V _{BUS} =3.3V, f = 1MHz, Any I/O Pin to GND		1.75	2	pF				

Notes:

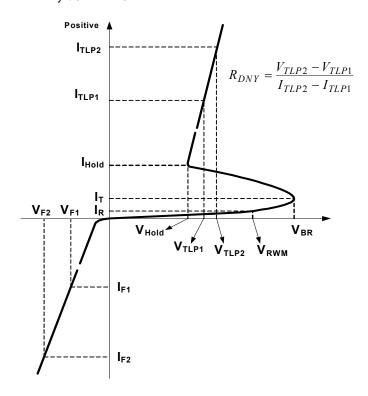
- 3. These specifications are guaranteed by design and characterization.
- 4. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.

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Electrical Characteristics

 T_A = 25°C unless otherwise specified. Any I/O Pin to GND.



	Pin 4 to Pin 7 (TX+, TX-, RX+, RX- of USB 3.1/3.2)									
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units				
V_{RWM}	Reverse Working Voltage				5.5	V				
V _{BR}	Reverse Breakdown Voltage	I _T = 100μA	6.6			V				
I _R	Reverse Leakage Current	V _T = Max, V _{RWM}			100	nA				
V _F	Forward Voltage		0.7	0.85	0.95	V				
	Clamping Voltage ⁽³⁾⁽⁴⁾ (100ns Transmission Line Pulse)	I _{TLP} = 1A I _{TLP} = -1A		1.5 -1.5		V				
V _{CL}		I _{TLP} = 16A I _{TLP} = -16A		6 -4						
R _{DNY}	Dynamic Resistance ⁽³⁾⁽⁴⁾	I _{TLP} =1 to 16A I _{TLP} =-1 to -16A			0.30 0.20	Ω				
I _{PP}	Peak Pulse Current ⁽³⁾ IEC61000-4-5 Surge 8/20μs	Any I/O Pin to GND GND to any I/O Pin			±6	А				
V _{CL}	Clamping Voltage ⁽³⁾ IEC61000-4-5 Surge 8/20μs	I _{PP} =1A I _{PP} =-1A		2 -2		V				
		I _{PP} =6A I _{PP} =-6A		6 -5						
CJ	Junction Capacitance	V _{I/O} = 1.65V, f = 1MHz, Any I/O Pin to GND		0.4	0.6	pF				

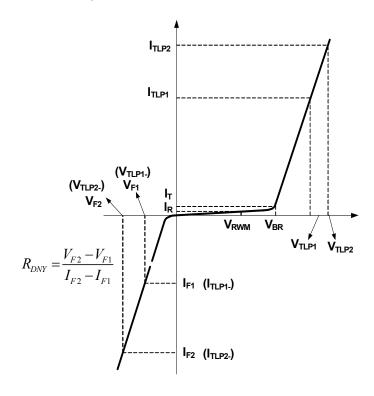
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Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified. Pin 2 to GND.



	Pin 2 (VBUS)									
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units				
V_{RWM}	Reverse Working Voltage				5.5	V				
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	6.6			V				
I _R	Reverse Leakage Current	V _T = Max, V _{RWM}			1	μΑ				
V _F	Forward Voltage		0.7	0.85	0.95	V				
V	Clamping Voltage ⁽³⁾⁽⁴⁾ (100ns Transmission Line Pulse)	I _{TLP} = 1A I _{TLP} = -1A		9 -1		. V				
V _{CL}		I _{TLP} = 16A I _{TLP} = -16A		12 -3						
R _{DNY}	Dynamic Resistance ⁽³⁾⁽⁴⁾	I _{TLP} =1 to 16A I _{TLP} =-1 to -16A			0.20 0.13	Ω				
I _{PP}	Peak Pulse Current ⁽³⁾ IEC61000-4-5 Surge 8/20μs	Any I/O Pin to GND GND to any I/O Pin			±15	Α				
V	Clamping Voltage ⁽³⁾ IEC61000-4-5 Surge 8/20μs	I _{PP} =1A I _{PP} =-1A		9 -1.3		- V				
V_{CL}		I _{PP} =15A I _{PP} =-15A		15 -3						
CJ	Junction Capacitance	V _{I/O} = 0V, f = 1MHz, Any I/O Pin to GND		120		pF				

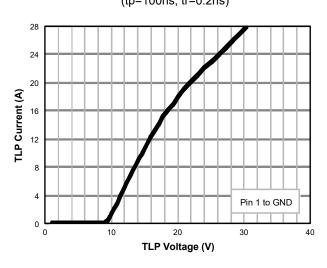
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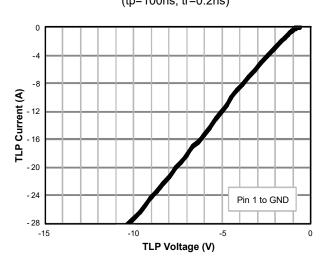


Typical Performance Characteristics

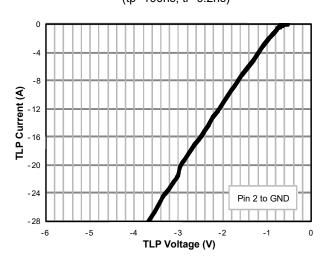
Positive Transmission Line Pulse (tp=100ns, tr=0.2ns)



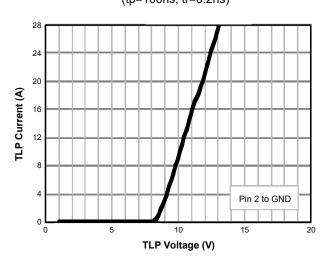
Negative Transmission Line Pulse (tp=100ns, tr=0.2ns)



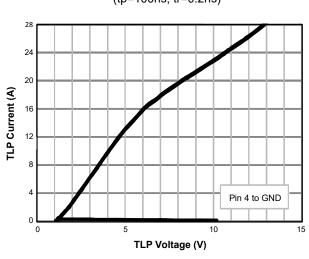
Negative Transmission Line Pulse (tp=100ns, tr=0.2ns)



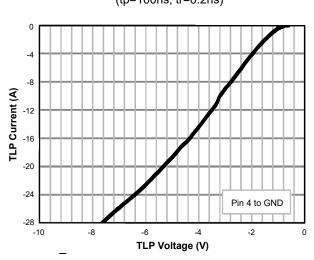
Positive Transmission Line Pulse (tp=100ns, tr=0.2ns)



Positive Transmission Line Pulse (tp=100ns, tr=0.2ns)



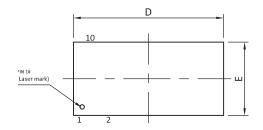
Negative Transmission Line Pulse (tp=100ns, tr=0.2ns)



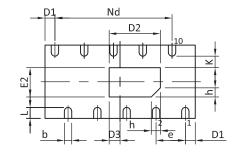
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Package Dimensions, DFN4.1x2.0-10L, EP1_S



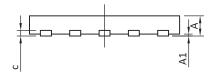




TOP VIEW

SIDE VIEW

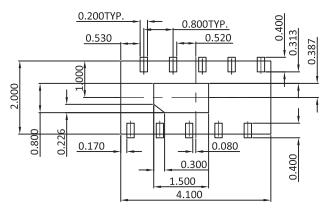
BOTTOM VIEW



SIDE VIEW

	DIMENS	ION IN MI	LLIMETRES	DIM	ENSION IN I	NCHS	
SYMBOLS	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.45	0.50	0.55	0.018	0.020	0.022	
A1		0.02	0.05		0.001	0.002	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	4.00	4.10	4.20	0.157	0.161	0.165	
D1	0.20	0.25	0.30	0.008	0.010	0.012	
D2	1.30	1.40	1.50	0.051	0.055	0.059	
D3	0.25	0.30	0.35	0.010	0.012	0.014	
е		0.80 BS0			0.031 BSC		
Nd		3.20 BSC			0.126 BSC		
Е	1.90	2.00	2.10	0.075	0.079	0.083	
E2	0.70	0.80	0.90	0.028	0.031	0.035	
K	0.20			0.008			
L	0.25	0.30	0.35	0.010	0.012	0.014	
h	0.15	0.20	0.25	0.006	0.008	0.010	

LAND PATTERN RECOMMENDATIONS



UNIT: mm

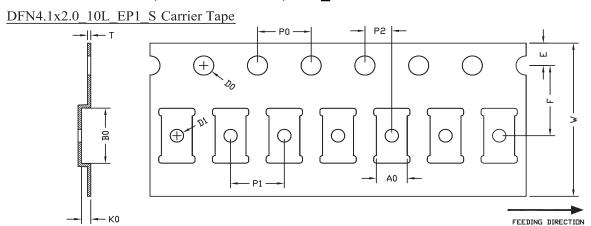
NOTES

1. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.

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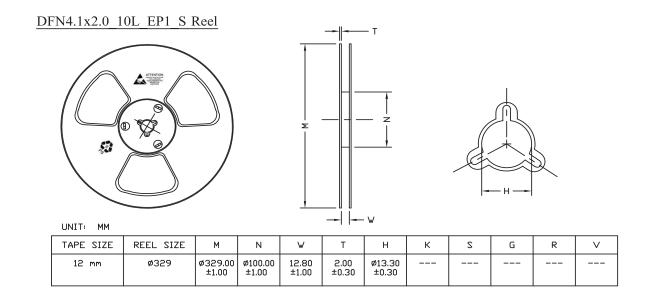


Tape and Reel Dimensions, DFN4.1x2.0-10L, EP1_S

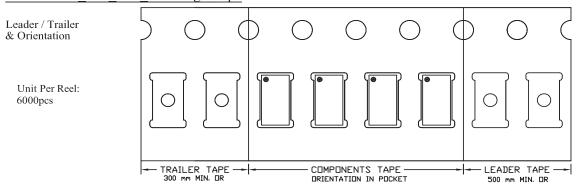


UNIT:	MM
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PACKAGE	A0	В0	К0	D0	D1	V	Ε	F	P0	P1	P2	Т
DFN4.1×2.0	2.30 ±0.05	4.30 ±0.05	0.70 ±0.05	1.50 +0.1 -0.0	1.00 Min.	12.00 +0.30 -0.10	1.75 ±0.10	5.50 ±0.05	4.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.25 ±0.03



DFN4.1x2.0_10L_EP1_S Package Tape

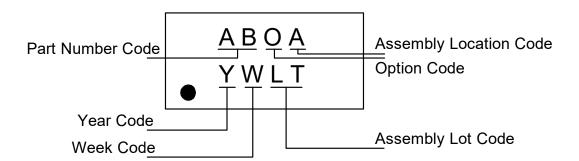


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Part Marking

AOZ8936DI (DFN4.1x2.0_10L)



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- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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